NSN 5961-00-515-3303

Fiig: A110a0

Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-515-3303 **Inclosure Material:** Glass **Overall Length:** 0.755 inches **Overall Height:** 0.070 inches **Overall Width:** 0.265 inches **Component Name And Quantity:** 2 transistor **Mounting Method: Terminal Semiconductor Material:** Silicon all semiconductor Voltage Rating In Volts Per Characteristic: 60.0 collector to base voltage, dc all semiconductor **Current Rating Per Characteristic:** 600.00 milliamperes source cutoff current all transistor **Power Rating Per Characteristic:** 350.0 milliwatts small-signal input power, common-collector preset all transistor **Special Features:** All transistor junction pattern arrangement: npn **Terminal Type And Quantity:** 6 pin Shelf Life: N/a **Unit Of Measure:** Demilitarization: No